



# EMB-945T

## Thermal Image Analysis Report

Report No:06E080003

Release Date: 02 / 24 / 2005

2005-02-24

Issue Stamp

Wenyuan Yang

Manager

Andrew Ku

Test Engineer

**I . Model Name: EMB-945T A0.1**

**II . Description: Intel 945GM (Calistoga) + ICH7M Mini ITX Board**

**III . Date: 02 / 24 / 2005**

**IV . Measure Site: AAEON QE Dept.**

**V . Issued by: Andrew Ku**

**VI.Equipment:**

**1. TVS-100 series by NIPPON AVIONICS CO., LTD.**

**VII. Simulation Environment:**

• **Temperature:**

**Component Side – 1: 22.8degrees C**

**Component Side – 2: 22.9 degrees C**

• **System Configuration :**

**BIOS ver :0.2**

**CPU: Intel® Core Duo T2500 2.0GHz**

**Memory: KINGMAX / ELPIDA/E5108AE-5C-E / SODDR2-533 /1G**

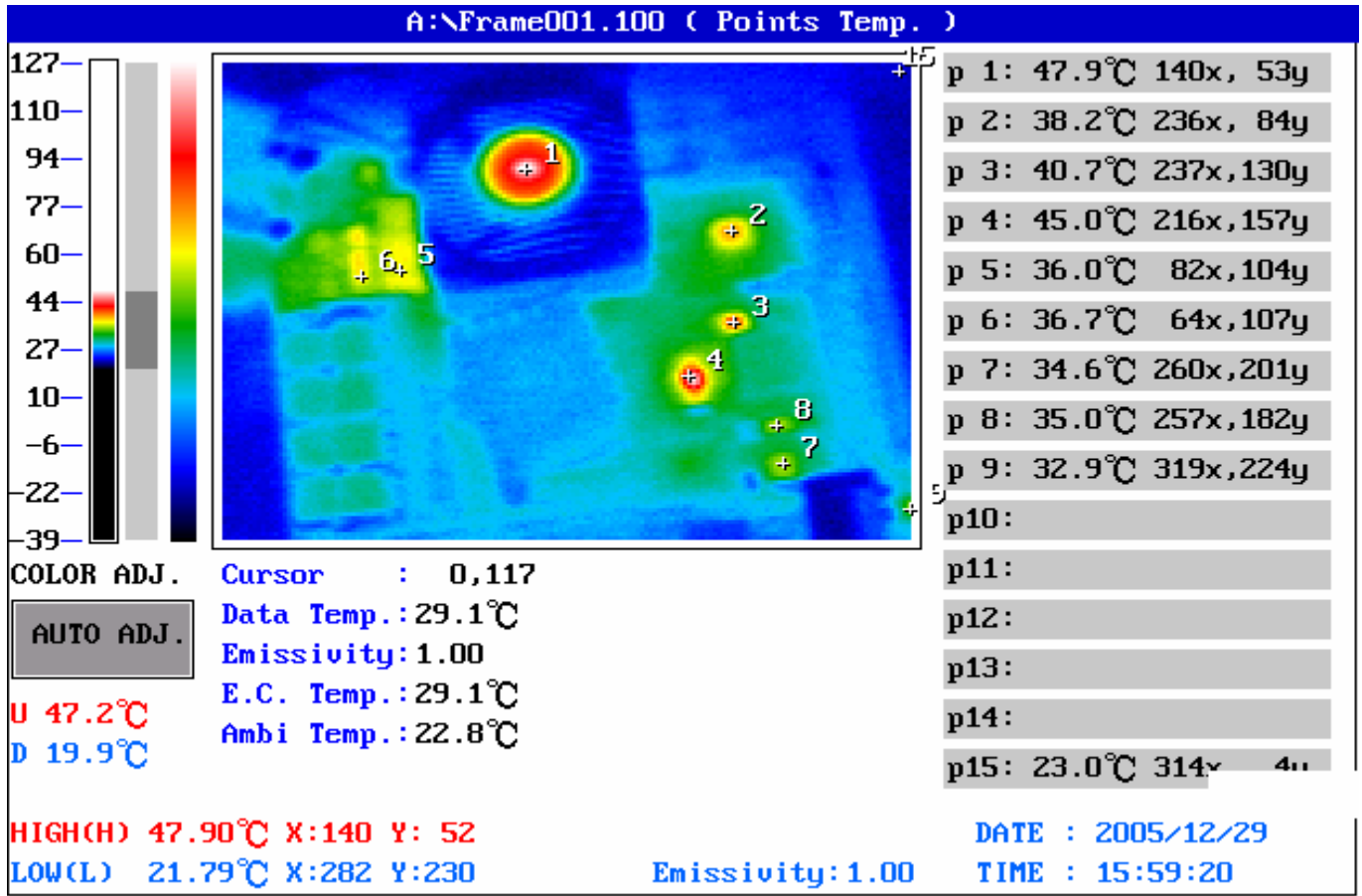
**HDD: MAXTOR 80GB**

• **Application Software: Windows 2000 run HCT9.5**

• **Take Picture Time: Power on 2 hours after**

## Temperature Profile Test:

### Component Side – 1:



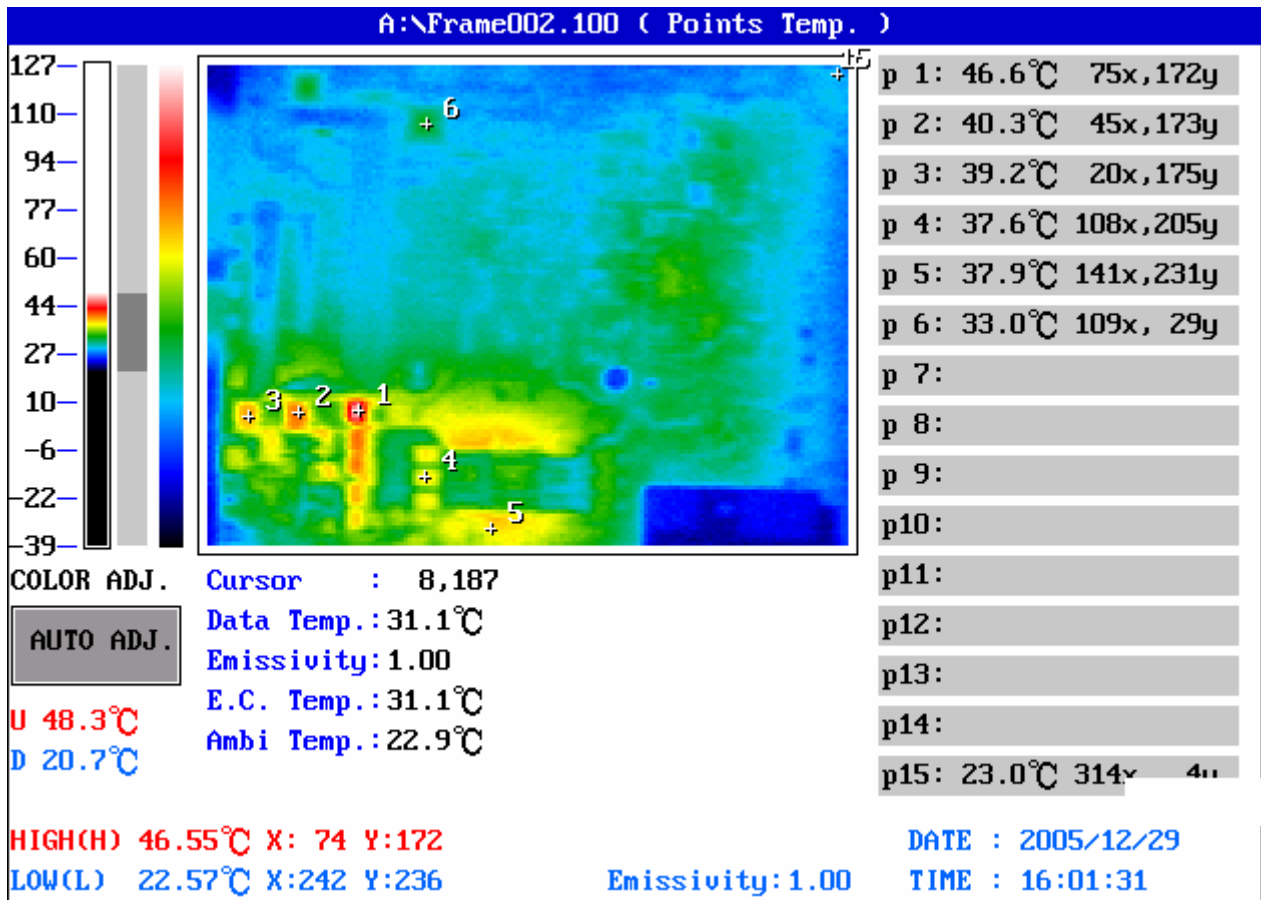
Point	Position	Describe	Tc	Tm (25°C)	Tm (60°C)	Note
1	U14	CPU FAN		47.9°C	82.9°C	
2	U15	IC.SMD.Chipset ICH7M.Intel.NH82801GBM SL8YB	-0°C~108°C	38.2°C	73.2°C	
3	U9	IC SKT PLCC.SMD.32P(9*7P).CATCH.2150-700-32	-55°C~150°C	40.7°C	75.7°C	
4	U4	(TF)IC.SMD.QFP128P Super I/O.ITE.IT8712F-A/IX-L	-30°C~100°C	45.0°C	80.0°C	
5	L15	INDUCTORS.0.6uH 25A.20%.SMD 2pin.TRIO.EB-60BM58H02	-10°C~135°C	36.0°C	71.0°C	
6	Q10	(TF)PWR.SMD.SO8.N-Channel.30V.12A.ANPEC.APM4410KC-TRL	-55°C~150°C	36.7°C	71.7°C	
7	U3	(TF)IC.SMDQFN64P.PCI-EGigaBitEthernet Chipset.Marvell.88E8053-A3-NNC1C000	-30°C~100°C	34.6°C	69.6°C	
8	L7	BEAD.30ohm(100MHz).+/-25%.DCR=0.04ohm.3A.0805.SMD.AG.CB201209 N-3A-300Y	-30°C~125°C	35.0°C	70.0°C	
9	U1	IC.SMDLQFP48Pin.6ChannelAC'97AudioCodec.REALTEK.ALC655-LF	-30°C~100°C	32.9°C	67.9°C	
10			-			
11						
12						
13						
14						
15		Ambient Temperature		22.8°C		

1. Operation Temperature (°C):  
 $T_c(\text{Case temp.}) = T_a(\text{Ambient Temp.}) \pm 30^\circ\text{C} = T_j(\text{Junction Temp.}) \pm 25^\circ\text{C}$

Note: The description in red states which temperature is over the specification of the device.

# Thermal Image Analysis

## Component Side -2:



Point	Position	Describe	Tc	Tm (25°C)	Tm (60°C)	Note
1	Q31	(TF)PWR.SMD.SO8.N-Channel.30V.12A.ANPEC.APM4410KC-TRL	-55°C~150°C	46.6°C	81.6°C	
2	Q30	(TF)PWR.SMD.TO-252.N-Channel PowerMosfet.ON SEMI.NTD60N02RT4G	-55°C~175°C	40.3°C	75.3°C	
3	Q29	(TF)PWR.SMD.TO-252.N-Channel PowerMosfet.ON SEMI.NTD60N02RT4G	-55°C~175°C	39.2°C	74.2°C	
4	Q37	PWR.SMD.SOT-23.P-Channel.EnhancementModeMOSFET.ANPEC.APM2301A	-25°C~150°C	37.6°C	72.6°C	
5	C656	(TF)EPCOS.150uF.6.3V.20%.D(7.3*4.3*1.9mm).25mOhm.SMD.EPCOS.B45294R1157M429	-30°C~130°C	37.9°C	72.9°C	
6	U21	(TF)PWR.SMD.SOT-251.1mA.High-SideSwitchwitFlag.RICHTEK.RT9702 A-PB	-20°C~100°C	33.0°C	68.0°C	
7						
8						
9						
10						
11						
12						
13						
14						
15		Ambient Temperature		22.9°C		

1. Operation Temperature (°C):

$$T_c(\text{Case temp.}) = T_a(\text{Ambient Temp.}) \pm 30^\circ\text{C} = T_j(\text{Junction Temp.}) \pm 25^\circ\text{C}$$

Note: The description in red states which temperature is over the specification of the device.